## 2SC5551A

# ON Semiconductor®

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### RF Transistor 30V, 300mA, fT=3.5GHz, NPN Single PCP

#### **Features**

High fT: (fT=3.5GHz typ)Large current: (IC=300mA)

• Large allowable collector dissipation (1.3W max)

#### **Specifications**

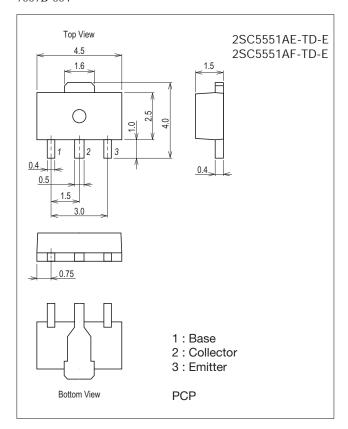
#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		40	V
Collector-to-Emitter Voltage	VCEO		30	V
Emitter-to-Base Voltage	VEBO		2	V
Collector Current	IC		300	mA
Collector Current (Pulse)	ICP		600	mA
Collector Dissipation	PC	When mounted on ceramic substrate (250mm <sup>2</sup> ×0.8mm)	1.3	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

#### **Package Dimensions**

unit : mm (typ) 7007B-004



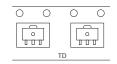
#### **Product & Package Information**

• Package : PCP

• JEITA, JEDEC : SC-62, SOT-89, TO-243

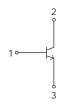
• Minimum Packing Quantity: 1,000 pcs./reel

#### Packing Type: TD Marking





#### **Electrical Connection**



#### Electrical Characteristics at Ta=25°C

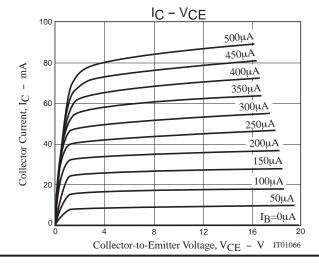
Parameter	Symbol	Conditions	Ratings			Unit	
Parameter	Symbol	Conditions	min	typ	max	Uill	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =20V, I <sub>E</sub> =0A			1.0	μΑ	
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =1V, I <sub>C</sub> =0A			5.0	μΑ	
DC Current Gain	hFE1	V <sub>CE</sub> =5V, I <sub>C</sub> =50mA	90		270		
	h <sub>FE</sub> 2	V <sub>CE</sub> =5V, I <sub>C</sub> =300mA	20				
Gain-Bandwidth Product	fŢ	V <sub>CE</sub> =5V, I <sub>C</sub> =50mA		3.5		GHz	
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		2.9	4.0	pF	
Reverse Transfer Capacitance	Cre	0 CB=100' I=1INIUZ		1.5		pF	
Collector-to-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	IC=50mA, IB=5mA		0.07	0.3	V	
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=50mA, IB=5mA		0.8	1.2	V	

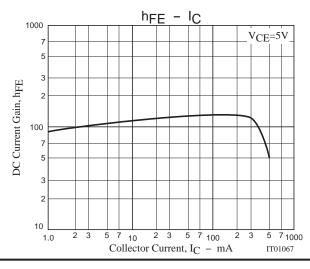
#### $^{\star}$ : The 2SC5551A is classified by 50mA $h_{\mbox{\scriptsize FE}}$ as follows :

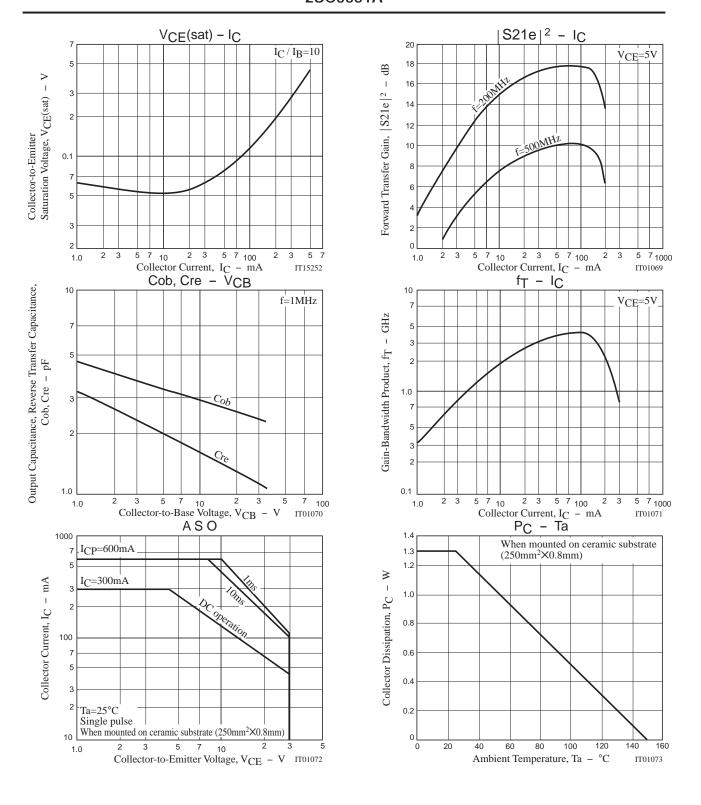
Rank	E	F		
hFE	90 to 180	135 to 270		

#### **Ordering Information**

Device	Package	Shipping	memo
2SC5551AE-TD-E	PCP	PCP 1,000pcs./reel	
2SC5551AF-TD-E	PCP	1,000pcs./reel	Pb Free





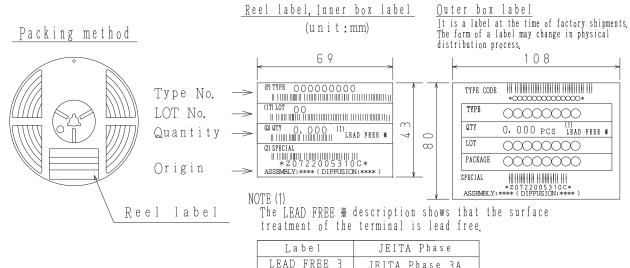


#### **Bag Packing Specification**

#### 2SC5551AE-TD-E, 2SC5551AF-TD-E

#### 1. Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	format
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
PCP	PCP	1, 000	4,000	24,000	4 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210

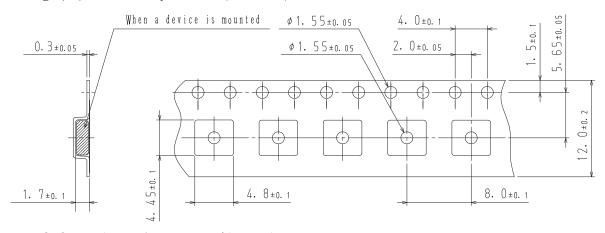


JEITA Phase 3A

JEITA Phase 3

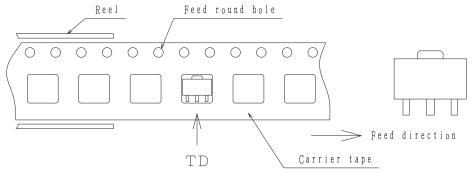
#### 7. Taping configuration

2-1. Carrier tape size (unit:mm)



LEAD FREE 4

2-2. Device placement direction



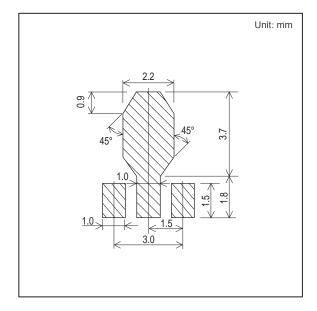
Those with pin 1 index on the feed hole side·····TD

#### **Outline Drawing**

2SC5551AE-TD-E, 2SC5551AF-TD-E

## Mass (g) Unit 0.058 For reference mm 4. 5±0. 1 1. 6±0. 2 \_ 1.5±0.1\_ 2. 5±0.1 4. 0±0. 2 1. 0±0. 2 0. 4+0. 08 0. 4±0. 03 0. 5<sup>+0. 05</sup> 1. 5±0. 2 3. O±0. 2 0. 75 0.10 \*1:Lot indication

#### **Land Pattern Example**



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